VSKD91.., VSKC91.., VSKJ91.., VSKE91.. Series

Vishay Semiconductors

ADD-A-PAK Generation VII Power Modules Standard Diodes, 100 A



PRODUCT SUMMARY				
I _{F(AV)}	100 A			
Туре	Modules - Diode, High Voltage			

MECHANICAL DESCRIPTION

The ADD-A-PAK generation VII, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

FEATURES

- High voltage
- Industrial standard package
- UL approved file E78996
 Low thermal resistance
- Designed and qualified for industrial level
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

BENEFITS

- Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- Up to 1600 V
- High surge capability
- Easy mounting on heatsink

ELECTRICAL DESCRIPTION

These modules are intended for general purpose high voltage applications such as high voltage regulated power supplies, lighting circuits, temperature and motor speed control circuits, UPS and battery charger.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	112 °C	100				
I _{F(RMS)}		157	А			
	50 Hz	2020	A			
FSM	60 Hz	2115				
l ² t	50 Hz	20.41	kA ² s			
1-1	60 Hz	18.63	KA-S			
l²√t		204.1	kA²√s			
V _{RRM}	Range	400 to 1600	V			
TJ		- 40 to 150	°C			
T _{Stg}		- 40 10 150	U			



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ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS								
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} MAXIMUM AT T _J = 150 °C mA				
	04	400	500					
	06	600	700					
	08	800	900					
VSK.91	10	1000	1100	10				
	12	1200	1300					
	14	1400	1500					
	16	1600	1700					

FORWARD CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS
Maximum average forward current at case temperature	I _{F(AV)}	180° condu	iction, half sine	wave	100 112	A °C
Maximum RMS forward current	I _{F(RMS)}	DC at 90 °C	case temperat	ure	157	U
	. (t = 10 ms	No voltage		2020	
Maximum peak, one-cycle forward,		t = 8.3 ms	reapplied	-	2115	А
non-repetitive surge current	IFSM	t = 10 ms	100 % V _{RRM}		1700	
		t = 8.3 ms	reapplied	Sinusoidal half wave,	1780	
	l ² t t = 8.3 ms t = 10 ms	t = 10 ms	No voltage reapplied	intitial T _J = T _J maximum	20.41	kA ² s
		t = 8.3 ms			18.63	
Maximum I ² t for fusing		t = 10 ms	100 % V _{RRM}		14.44	
		t = 8.3 ms	reapplied		13.18	
Maximum I ² \sqrt{t} for fusing	l²√t	t = 0.1 ms t	o 10 ms, no vol	tage reapplied	204.1	kA²√s
Low level value of threshold voltage	V _{F(TO)1}	(16.7 % x π	$x I_{F(AV)} < I < \pi x$	(I _{F(AV)}), T _J = T _J maximum	0.76	v
High level value of threshold voltage	V _{F(TO)2}	$(I > \pi x I_{F(AV)}), T_J = T_J maximum$			0.89	v
Low level value of forward slope resistance	r _{f1}	(16.7 % x π x $I_{F(AV)} < I < \pi$ x $I_{F(AV)}$), $T_J = T_J$ maximum			2.4	mΩ
High level value of forward slope resistance	r _{f2}	$(I > \pi \times I_{F(AV)}), T_J = T_J maximum$			2.05	11122
Maximum forward voltage drop	V _{FM}	$I_{FM} = \pi \times I_{F(x)}$	_{AV)} , T _J = 25 °C,	t _p = 400 μs square wave	1.55	V

BLOCKING							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum peak reverse leakage current	I _{RRM}	T _J = 150 °C	10	mA			
Maximum RMS insulation voltage	V _{INS}	50 Hz	3000 (1 min) 3600 (1 s)	V			

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THERMAL AND MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Junction and storage tempe	erature range	T _J , T _{Stg}		- 40 to 150	°C		
Maximum internal thermal r junction to case per leg	esistance,	R _{thJC}	DC operation	0.22	°C/W		
Typical thermal resistance, case to heatsink per module		R _{thCS}	Mounting surface flat, smooth and greased	0.1	C/W		
Mounting torque ± 10 %busbar			A mounting compound is recommended and the torque should be rechecked after a period of	4	Nm		
			3 hours to allow for the spread of the compound.	3	INITI		
				75	g		
Approximate weight	Approximate weight			2.7	oz.		
Case style			JEDEC	ADD-A-PAK Ger	n. VII (TO-240AA)		

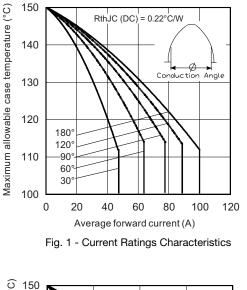
DEVICES	SINE HALF WAVE CONDUCTION					RECTANGULAR WAVE CONDUCTION					
DEVICES	180°	120°	90°	60°	30°	180°	120°	90°	60°	30 °	
VSK.91	0.057	0.068	0.087	0.12	0.177	0.045	0.073	0.093	0.123	0.178	°C/W

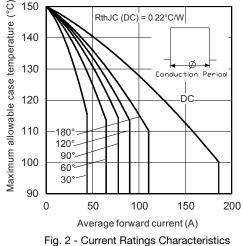
Note

Table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

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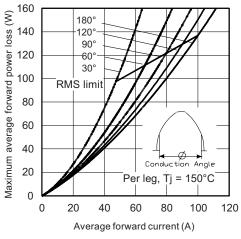


Fig. 3 - Forward Power Loss Characteristics

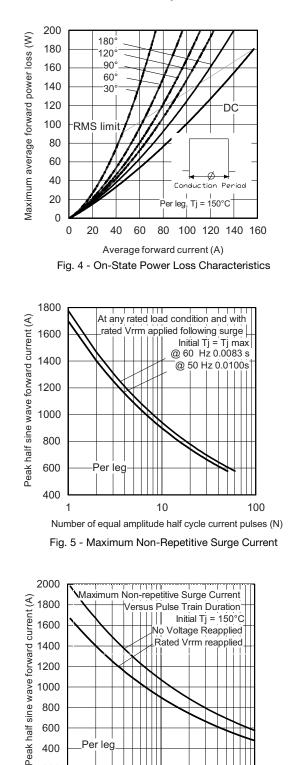


Fig. 6 - Maximum Non-Repetitive Surge Current

Pulse train duration (s)

0.1

Per leg

400

200

0.01

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VSKD91.., VSKC91.., VSKJ91.., VSKE91.. Series www.vishay.com Vishay Semiconductors 200 RthSA = 0.1 °C/W Maximum total forward power loss (W) 180 0.3 °C/W 0.5 °C/W 160 0.7 °C/W _1°C/W 140 1.5 °C/W 180 120 °C/W 3 (Sine) DC 100 80 60 40 SK.91 Ser Per leg 20 Tj = 150°C 0 0 20 40 60 80 100 120 140 160 20 40 60 80 100 120 140 160 Total RMS output current (A) Maximum allowable ambient temperature (°C) Fig. 7 - Forward Power Loss Characteristics 700 RthSA = 0.2 °C/W 0.3 °C/W 180 600 0.4 °C/W Maximum total power loss (W) (sine) 0.5 °C/W 180 500 -0.7 °C/w (rect) 1°C/W 1.5 °C/M 400 3 °C/W 300 200 2 x VSK.91 Series 100 single phase bridge connected Tj = 150°C 0 0 50 100 150 20 40 60 80 100 120 140 160 200 Maximum allowable ambient temperature (°C) Total output current (A) Fig. 8 - Forward Power Loss Characteristics 900 RthSA = 0.1 °C/W .0.2 °C/W 800 0.3 °C/W Maximum total power loss (W) 700 -0.5 °C/W ,0.7 °C/W 600 1°C/W 120 /3 °C/W 500 (rect) 400 300 200 3 x VSK.91 Series 100 three phase bridge connected Tj = 150°C 0 0 60 80 100 120 140 160 50 100 150 200 250 300 20 40 Total output current (A) Maximum allowable ambient temperature (°C)

Fig. 9 - Forward Power Loss Characteristics

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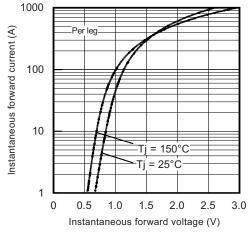


Fig. 10 - Forward Voltage Characteristics

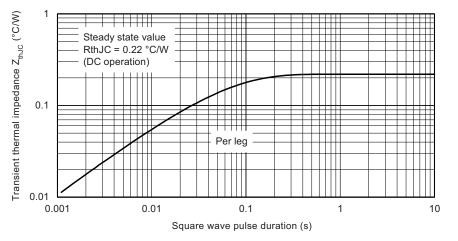


Fig. 11 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

Device code VSK D 91 1 16 2 (3) 1 4 Module type 2 Circuit configuration (see Circuit Configuration table) 3 Current code (100 A) Voltage code (see Voltage Ratings table) 4

Note

To order the optional hardware go to <u>www.vishay.com/doc?95172</u>

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CIRCUIT CONFIGURATION						
CIRCUIT DESCRIPTION	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING				
Two diodes doubler circuit	D					
Two diodes common cathodes	С					
Two diodes common anodes	J	VSKJ + (2) + (2)				
Single diode	E					

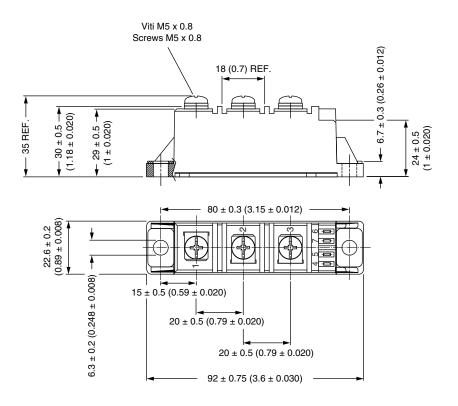
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95369			

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ADD-A-PAK Generation VII - Diode

DIMENSIONS in millimeters (inches)





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